

IPI90R1K0C3XKSA1

IPI90R1K0C3XKSA1 Information

www.hakeme		IPI90R1K0C3XKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 900V 5.7A TO-262 TO-262-3 Long Leads, I2Pak, TO-262AA For the pricing/inventory/lead time, please contact us	
For Reference	Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPI90R1K0C3XKSA1 Specifications

Manufacturer Part Number	IPI90R1K0C3XKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-262-3 Long Leads, I2Pak, TO-262AA
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	900V
Current - Continuous Drain (Id) @ 25°C	5.7A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 370µA
Gate Charge (Qg) (Max) @ Vgs	34nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	850pF @ 100V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	89W (Tc)
Rds On (Max) @ Id, Vgs	1 Ohm @ 3.3A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO262-3
Package / Case	TO-262-3 Long Leads, I2Pak, TO-262AA
	Report errors?

IPI90R1K0C3XKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPI90R1K0C3XKSA1 Payment Methods



If you have any question about IPI90R1K0C3XKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com